



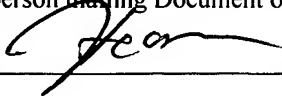
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

I hereby certify that this correspondence is being deposited  
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Amendment, Commissioner for Patents, P.O. Box 1450,  
Alexandria, VA 22313-1450 on January 20, 2006  
(Date of Deposit)

Harold C. Moore

Name of person mailing Document or Fee

  
Signature

January 20, 2006

Date of Signature

Re:	Application of:	Taravade et al.
	Serial No.:	10/733,034
	Filed:	December 11, 2003
	For:	Method of Fabricating an Integral Capacitor and Gate Transistor Having Nitride and Oxide Polish St Layers Using Chemical Mechanical Polishing Eliminators
	Group Art Unit.:	1765
	Examiner:	Patricia Ann George
	MMB Docket No.:	1003-0637

TRANSMITTAL OF RESPONSE TO OFFICE ACTION

Please find for filing in connection with the above patent application the  
following:

1. Response to Office Action; and
2. One (1) return post card.

\* The fee has been calculated as shown below.

CLAIMS AS AMENDED				
	Claims Remaining After Amendment	Highest No. Paid For	Fee Calculation	Addit Fee
Total Claims	5	20	0 X 50	\$ 0.00
Independent Claims	1	3	0 X 200	\$ 0.00
Total Additional Fee Required				\$ 0.00

Please charge any fee deficiency, or credit any overpayment, to Deposit Account No. 13-0014; but not to include any payment of issue fees.

Respectfully Submitted,

MAGINOT, MOORE & BECK



January 20, 2006

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Indianapolis, Indiana 46204-5115

Enclosures



*ifw*

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Examiner: George, Patricia Ann  
LSI Docket No.: 01-916/ID  
MMB Docket No.: 1003-0637

RESPONSE TO OFFICE ACTION

Sir:

In response to the Office Action dated October 20, 2005 for the above-identified patent  
application, please amend the application as follows:

Amendments to the Claims begin at page 2 of this document.

Remarks begin at page 5 of this document.